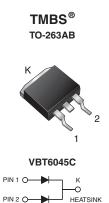
RoHS COMPLIANT

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Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.33$ V at $I_F = 10$ A



PRIMARY CHARACTERISTICS				
Package TO-263AB				
I _{F(AV)}	2 x 30 A			
V _{RRM}	45 V			
I _{FSM}	320 A			
V_F at I_F = 30 A	0.47 V			
T _J max.	150 °C			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- HALOGEN • Meets MSL level 1, per J-STD-020, LF maximum FREE peak of 245 °C
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT6045C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	٨	
	per diode		30	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	320	А	
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V	
	I _F = 15 A			0.47	-		
	I _F = 30 A			0.54	0.64		
	I _F = 10 A	T _A = 125 °C		0.33	-		
	I _F = 15 A			0.37	-		
	I _F = 30 A			0.47	0.56		
Reverse current per diode	V - 45 V	T _A = 25 °C	I _R ⁽²⁾	-	3000	μA	
	$V_{\rm R} = 45 \text{ V}$ $T_{\rm A} = 1000 \text{ T}$	T _A = 125 °C		18	50	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT64045C	UNIT	
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	1.5	°C/W	
	per device		0.8		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT6045C-M3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT6045C-M3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

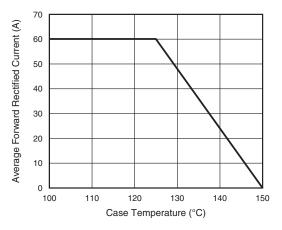


Fig. 1 - Maximum Forward Current Derating Curve

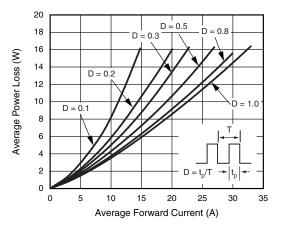
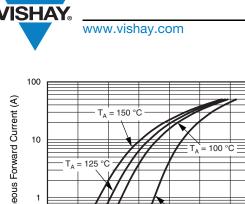


Fig. 2 - Forward Power Loss Characteristics Per Diode

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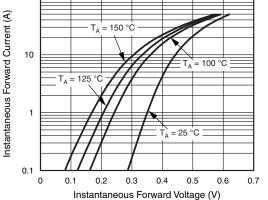


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

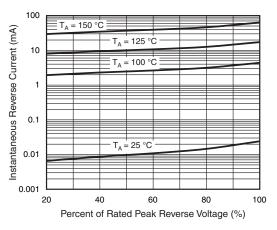
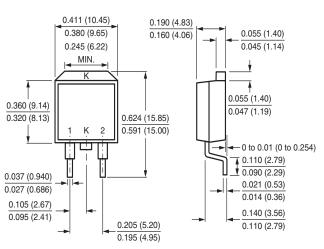


Fig. 4 - Typical Reverse Characteristics Per Diode





TO-263AB

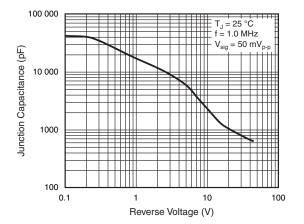


Fig. 5 - Typical Junction Capacitance Per Diode

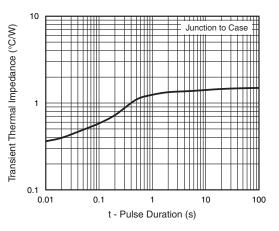
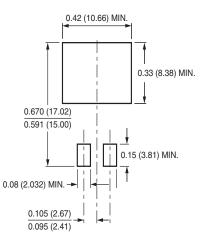


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Mounting Pad Layout



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